RELIABILITY REPORT

FOR

MAX664xxA

PLASTIC ENCAPSULATED DEVICES

May 15th, 2003

MAXIM INTEGRATED PRODUCTS

120 SAN GABRIEL DR.

SUNNYVALE, CA 94086

Written by

Jim Pedicord Quality Assurance Reliability Lab Manager 1

Reviewed by

Bryan J. Preeshl Quality Assurance Executive Director

Conclusion

The MAX664 successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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I. Device Description

A. General

The MAX664 CMOS voltage regulator has a maximum quiescent current of $12\mu A$. It can be used either as a 5V, fixed output regulator with no additional components, or it can be adjusted from 1.3V to 16V using two external resistors. Fixed or adjustable operation is automatically selected via the V_{SET} input. The MAX664, ideally suited for battery powered systems, has an input voltage range of 2 to 16.5V, an output current capability of 40mA, and can operated with low input-output differentials. Other features include current limiting and low power shut down.

The MAX664 negative regulator is both pin and electrically compatible with the ICL7664 and can plug-in replace this device, improving performance and eliminating the need for external resistors in 5V applications.

B. Absolute Maximum Ratings

<u>ltem</u>	Rating
Input Supply Voltage	+18V
Terminal Voltage	
Pins 1, 2, 3, 5, 6	(GND - 0.3V) to $(V_{IN} + 0.3V)$
Output Sink Current, Pin 7	-20mA
Storage Temp.	-65°C to +150°C
Lead Temp. (10 sec.)	+300°C
Power Dissipation	450mW
Derates above +70°C	6.00mW/°C
Continuous Power Dissipation (TA = +70°C)	
8-Pin SO	450mW
8-Pin DIP	625mW
Derates above +70°C	
8-Pin SO	6.0mW/°C
8-Pin DIP	8.23mW/°C

II. Manufacturing Information

A. Description/Function: Dual Mode™ 5V/ Programmable Micropower Voltage Regulator

B. Process: M6 (SMG) - 6 micron metal gate CMOS

C. Number of Device Transistors: 45

D. Fabrication Location: Oregon, USA

E. Assembly Location: Philippines, Malaysia, or Thailand

F. Date of Initial Production: December, 1986

III. Packaging Information

A. Package Type: 8-Lead Small Outline 8-Lead PDIP B. Lead Frame: Copper Copper C. Lead Finish: Solder Plate Solder Plate D. Die Attach: Silver-filled Epoxy Silver-filled Epoxy E. Bondwire: Gold (1.3 mil dia.) Gold (1.3 mil dia.) F. Mold Material: Epoxy with silica filler Epoxy with silica filler G. Assembly Diagram: # 05-0701-0756 # 05-0701-0755 H. Flammability Rating: Class UL94-V0 Class UL94-V0 I. Classification of Moisture Sensitivity per JEDEC standard JESD22-A112: Level 1 Level 1

IV. Die Information

A. Dimensions: 90 x 66 mils

B. Passivation: Si₃N₄/SiO₂ (Silicon nitride/ Silicon dioxide)

C. Interconnect: Aluminum/Si (Si = 1%)

D. Backside Metallization: None

E. Minimum Metal Width: 6 microns (as drawn)

F. Minimum Metal Spacing: 6 microns (as drawn)

G. Bondpad Dimensions: 5 mil. Sq.

H. Isolation Dielectric: SiO₂

I. Die Separation Method: Wafer Saw

V. Quality Assurance Information

A. Quality Assurance Contacts: Jim Pedicord (Manager, Rel Operations)

Bryan Preeshl (Executive Director) Kenneth Huening (Vice President)

B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.

0.1% For all Visual Defects.

C. Observed Outgoing Defect Rate: < 50 ppm

D. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in **Table 1**. Using these results, the Failure Rate (λ) is calculated as follows:

$$\lambda = \underbrace{\frac{1}{\text{MTTF}}}_{\text{F}} = \underbrace{\frac{1.83}{192 \text{ x } 4389 \text{ x } 480 \text{ x } 2}}_{\text{Temperature Acceleration factor assuming an activation energy of } \underbrace{\text{Chi square value for MTTF upper limit}}_{\text{C}}$$

$$\lambda = 2.26 \times 10^{-9}$$

 λ = 2.26 F.I.T. (60% confidence level @ 25°C)

This low failure rate represents data collected from Maxim's reliability monitor program. In addition to routine production Burn-In, Maxim pulls a sample from every fabrication process three times per week and subjects it to an extended Burn-In prior to shipment to ensure its reliability. The reliability control level for each lot to be shipped as standard product is 59 F.I.T. at a 60% confidence level, which equates to 3 failures in an 80 piece sample. Attached Burn-In Schematic (Spec. # 06-1794) shows the static Burn-In circuit. Maxim performs failure analysis on any lot that exceeds this reliability control level. Maxim also performs quarterly 1000 hour life test monitors. This data is published in the Product Reliability Report (RR-1M).

B. Moisture Resistance Tests

Maxim pulls pressure pot samples from every assembly process three times per week. Each lot sample must meet an LTPD = 20 or less before shipment as standard product. Additionally, the industry standard 85°C/85%RH testing is done per generic device/package family once a quarter.

C. E.S.D. and Latch-Up Testing

The PS84-1 die type has been found to have all pins able to withstand a transient pulse of ± 2500 V, per Mil-Std-883 Method 3015 (reference attached ESD Test Circuit). Latch-Up testing has shown that this device withstands a current of ± 100 mA.

Table 1 Reliability Evaluation Test Results

MAX664xxA

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	PACKAGE	SAMPLE SIZE	NUMBER OF FAILURES
Static Life Test	(Note 1)				
	Ta = 135°C Biased Time = 192 hrs.	DC Parameters & functionality		480	0
Moisture Testin	g (Note 2)				
Pressure Pot	Ta = 121°C P = 15 psi. RH= 100% Time = 168hrs.	DC Parameters & functionality	SO DIP	77 77	0
85/85	Ta = 85°C RH = 85% Biased Time = 1000hrs.	DC Parameters & functionality		77	0
Mechanical Stre	ess (Note 2)				
Temperature Cycle	-65°C/150°C 1000 Cycles Method 1010	DC Parameters & functionality		77	0

Note 1: Life Test Data may represent plastic DIP qualification lots. Note 2: Generic Package/Process data

Attachment #1

TABLE II. Pin combination to be tested. 1/2/

	Terminal A (Each pin individually connected to terminal A with the other floating)	Terminal B (The common combination of all like-named pins connected to terminal B)
1.	All pins except V _{PS1} 3/	All V _{PS1} pins
2.	All input and output pins	All other input-output pins

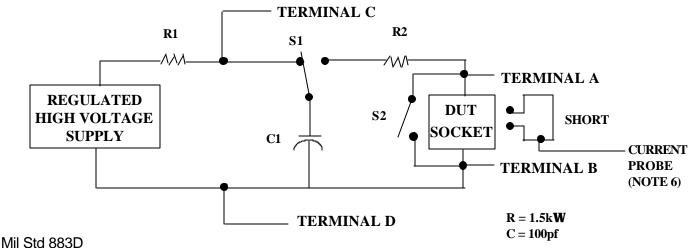
- Table II is restated in narrative form in 3.4 below.
- No connects are not to be tested.

 Repeat pin combination I for each named Power supply and for ground

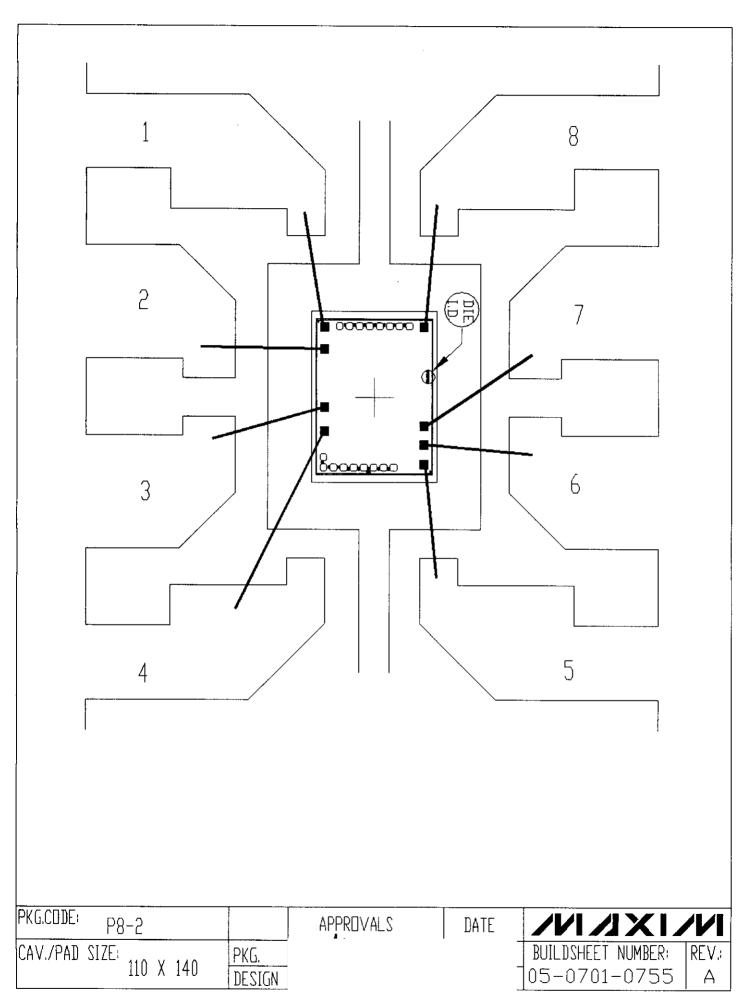
(e.g., where V_{PS1} is V_{DD} , V_{CC} , V_{SS} , V_{BB} , GND, $+V_{S}$, $-V_{S}$, V_{REF} , etc).

3.4 Pin combinations to be tested.

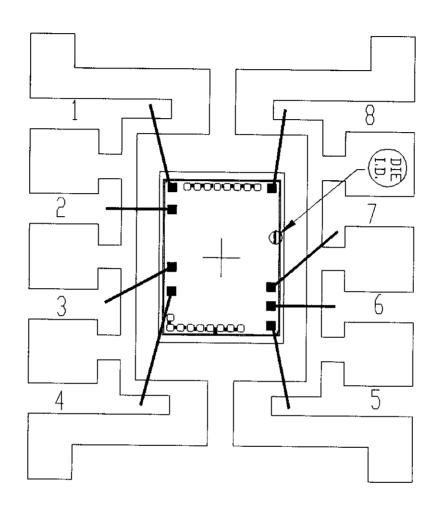
- Each pin individually connected to terminal A with respect to the device ground pin(s) connected a. to terminal B. All pins except the one being tested and the ground pin(s) shall be open.
- Each pin individually connected to terminal A with respect to each different set of a combination b. of all named power supply pins (e.g., V_{SS1} , or V_{SS2} or V_{SS3} or V_{CC1} , or V_{CC2}) connected to terminal B. All pins except the one being tested and the power supply pin or set of pins shall be open.
- Each input and each output individually connected to terminal A with respect to a combination of C. all the other input and output pins connected to terminal B. All pins except the input or output pin being tested and the combination of all the other input and output pins shall be open.



Method 3015.7 Notice 8



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PKG.CODE: S8-4		APPROVALS	DATE	/VI /1
CAV./PAD SIZE: 90 X 130	PKG. DESIGN		F	BUILDSHEET NU 05-0701-0

NIXI	
BUILDSHEET NUMBER:	REV.:
05-0701-0756	А

